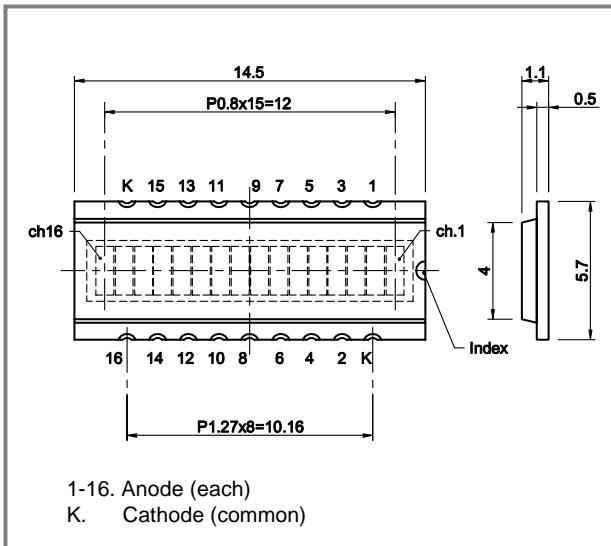


Features

- 16 channel array
- Transparent epoxy mold SMD package

Applications

- Optical switches
- Optical encoder
- Pulse detectors
- Sensors and industrial controls

Dimensions (unit: mm)**Absolute Maximum Ratings**

Parameter	Symbol	Value	Unit	Note
Reverse voltage	V _R	15	V	
Reverse current	I _R	500	μA	
Forward current	I _F	10	mA	
Operating temperature	T _{opr}	-20 to +80	°C	Avoid dew condensation
Storage temperature	T _{stg}	-30 to +100	°C	Avoid dew condensation

Electrical and Optical Characteristics (Ta=25 °C unless otherwise noted)

Parameter	Symbol	Min.	Typ.	Max	Unit	Test Conditions
Active area	S		0.74 x 2.0		mm ²	
Sensitive wavelength	λ	400	900(λ _p)	1000	nm	λ _p =Peak wavelength
Responsivity	R	-	0.54	-	A/W	λ=850nm
Cross talk	I _{sh}	-	-	-10	dB	λ=850nm, 20μm dia.
Dark current	I _D	-	-	1	nA	V _R =5V
Terminal capacitance	C _t	-	30	-	pF	V _R =0V, f=1MHz

Silicon Photodiode Array

KDA16S

